

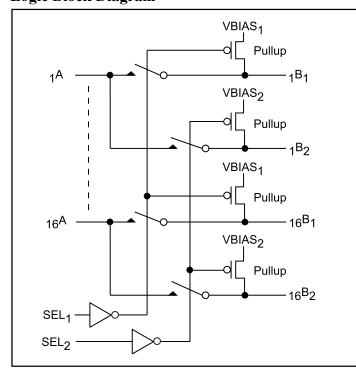
PI3C32160C

# 3.3V, High-Bandwidth, 16-Bit to 32-Bit, Demux PCI Hot-Plug Bus Switch w/ Undershoot Protection

#### **Product Features**

- R<sub>ON</sub> is 5Ω typical
- Pullup on B1 and B2 ports
- Undershoot protection on A-port only
- Low Power: 70µA typical
- Industrial Operation Temperature: -40°C to +85°C
- Near Zero propagation delay
- Switching speed: 5ns max.
- Channel on capacitance: 15pF max.
- V<sub>CC</sub> Operating Range: +2V to +3.6V
- ESD>2000V . . . Human Body Model
- >100 MHz bandwidth (or clock rate) at 20pF load capacitance
- Packages available: 56-pin TSSOP (A56)

## Logic Block Diagram



#### **Truth Table**

Function	SEL <sub>1</sub>	SEL <sub>2</sub>
nA to nB <sub>1</sub>	L	Н
nA to nB <sub>2</sub>	Н	L
$nA$ to $nB_1$ and $nB_2$	L	L
$nB_1$ , $nB_2 = V_{BIAS}$	Н	Н

## **Product Description**

Pericom Semiconductor's PI3C series of bus switch circuits are produced using the Company's advanced submicron CMOS technology, achieving industry leading performance.

The PI3C32160C is a 16- to 32-bit demultiplexer bus switch. Industry leading advantages include a propagation delay of 250ps, resulting from  $5\Omega$  channel resistance and low I/O capacitance. A1 port demultiplexes to either 1B and 2B or to both. The switch is bidirectional.

### **Application**

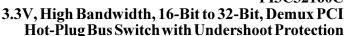
Provides PCI Hot Plugging.

### **Pin Description**

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r				
1B1 [	1		56	] 1A
2B1 [	2	$\overline{}$	55	<b>]</b> 1B2
2A 🛭	3		54	<b>]</b> 2B2
3B1 [	4		53	] 3A
4B1 🛭	5		52	<b>]</b> 3B2
4A [	6		51	] 4B2
5B1 [	7		50	<b>]</b> 5A
6B1 [	8		49	<b>]</b> 5B2
6A 🛭	9		48	<b>]</b> 6B2
7B1 [	10		47	] 7A
8B1 [	11		46	<b>]</b> 7B2
8A 🛭	12	# 6 D1	45	<b>]</b> 8B2
GND [	13	56-Pin	44	] GND
VCC [	14	A56	43	] Vcc
9B1 🛭	15		42	<b>」</b> 9A
10B1 🛭	16		41	<b>]</b> 9B2
10A 🛭	17		40	<b>」</b> 10B2
11B1 [	18		39	] 11A
12B1 🛭	19		38	<b>」</b> 11B2
12A 🛭	20		37	<b>」</b> 12B2
13B1 🛭	21		36	<b>」</b> 13A
14B1 🛭	22		35	<b>」</b> 13B2
14A [	23		34	<b>]</b> 14B2
15B1 🛭	24		33	<b>」</b> 15A
16B1 🛭	25		32	<b>」</b> 15B2
16A 🛭	26		31	<b>」</b> 16B2
VBIAS1	27		30	J ∨BIAS2
SEL1 [	28		29	J SEL2
'				•

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#### **Maximum Ratings**

(Above which the useful life may be impaired. For user guidelines, not tested.)

Storage Temperature65°C to +150°C
Ambient Temperature with Power Applied40°C to +85°C
Supply Voltage to Ground Potential (Inputs & Vcc Only)0.5Vto+7.0V
Supply Voltage to Ground Potential (Outputs & D/O Only)0.5V to +7.0V
DC Input Voltage0.5V to +7.0V
DC Output Current
Power Dissipation

#### Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

### **DC Electrical Characteristics** (Over the Operating Range, $T_A = -40^{\circ}\text{C}$ to $+85^{\circ}\text{C}$ , $V_{CC} = 3.3\text{V} \pm 10\%$ )

Parameters	Description	Test Conditions(1)	Min.	<b>Typ.</b> (2)	Max.	Units
$V_{\mathrm{IH}}$	Input HIGH Voltage	Guaranteed Logic HIGH Level	2.0	_	_	V
V <sub>IL</sub>	Input LOW Voltage	Guaranteed Logic LOW Level	-0.5	_	0.8	v
$I_{\mathrm{IH}}$	Input HIGH Current	$V_{CC} = Max., VIN = V_{CC}$			±1	
$I_{\mathrm{IL}}$	Input LOW Current	$V_{CC} = Max., VIN = GND$			±1	μA
Iozh	High-Impedence Output Current	$A = 0V$ or $V_{CC}$ Max., $VBIAS_1 = VBIAS_2 = 2.4V$	_	_	±1	μ. 1
I <sub>OZL</sub>	Low Impedance Output Current	$B = 0V$ or $V_{CC}$ Max., $VBIAS_1 = VBIAS_2 = 2.4V$	-0.2	_	-2	mA
V <sub>IK</sub>	Clamp diode Voltage	$V_{CC} = Min., I_{IN} = -18mA$	_	-0.70	-1.8	V
Ron	Switch On Resistance <sup>(4)</sup>	$V_{CC} = Min., V_{IN} = 0.0V$ $I_{ON} = 48mA$ or $64mA$		5	7	0
		$\begin{array}{c} V_{CC} = Min.,  V_{IN} = 2.4V \\ I_{ON} = 15mA \end{array}$	_	8	15	Ω

## Capacitance ( $T_A = 25$ °C f=1 MHz)

Parameters <sup>(5)</sup>	Description	Test Conditions	Тур.	Units	
C <sub>IN</sub>	Input Capacitance		3.5		
C <sub>ON</sub>	A/B Capacitance, Switch ON	V OV	12	ωE	
$C_{ m OFF}$	A Capacitance, Switch OFF $V_{IN} = 0V$		9	pF	
C <sub>OFF</sub>	B Capacitance, Switch OFF		4.5		

#### **Notes:**

- 1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device type.
- 2. Typical values are at  $V_{CC} = 3.3V$ ,  $T_A = 25$ °C ambient and maximum loading.
- 3. Not more than one output should be shorted at one time. Duration of the test should not exceed one second.
- 4. Measured by the voltage drop between A and B pin at indicated current through the switch. ON resistance is determined by the lower of the voltages on the two (A,B) pins.

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5. This parameter is determined by device characterization but is not production tested.

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#### **ADVANCE INFORMATION**





3.3V, High Bandwidth, 16-Bit to 32-Bit, Demux PCI Hot-Plug Bus Switch with Undershoot Protection

### **Power Supply Characteristics**

Parameters	Description	Test Conditions(1)	Min.	<b>Typ.</b> <sup>(2)</sup>	Max.	Units
$I_{CC}$	Quiescent Power Supply Current	$V_{CC} = Max., V_{IN} = GND \text{ or } V_{CC}$	_	260	500	
$\Delta I_{CC}$	Supply Current per Input @ TTL HIGH	$V_{CC} = Max., V_{IN} = 3.0V^{(3)}$	_	_	750	μА

#### Notes:

- 1. For Max. or Min. conditions, use appropriate value specified under Electrical Characteristics for the applicable device.
- 2. Typical values are at  $V_{CC} = 3.3V$ ,  $+25^{\circ}C$  ambient.
- 3. Per TTL driven input (control inputs only); A and B pins do not contribute to I<sub>CC</sub>.
- 4. This current applies to the control inputs only and represent the current required to switch internal capacitance at the specified frequency. The A and B inputs generate no significant AC or DC currents as they transition. This parameter is not tested, but is guaranteed by design.

## PI3C32160C Switching Characteristics Over Operating Range

Parameters	Description	Conditions <sup>(1)</sup>		Com.		TI
				Min.	Max.	Units
t <sub>PLH</sub> t <sub>PHL</sub>	Propogation Delay <sup>(2,3)</sup> Ax to Bx, Bx to Ax	$C_{L} = 50pF$ $R_{L} = 500\Omega$		_	0.25	
t <sub>PZH</sub>	Bus Enable Time SEL to Ax or Bx  Bus Disable Time SEL to Ax or Bx	$C_L = 50 pF$ $R_L = 500 \Omega$	VBIAS = GND	1.3	5.0	ns
t <sub>PZL</sub>			VBIAS = 3V			
t <sub>PHZ</sub>			VBIAS = GND			
$t_{PLZ}$			VBIAS = 3V	0.5	5.0	

### Notes:

- 1. See test circuit and waveforms.
- 2. This parameter is guaranteed but not tested on Propagation Delays.
- 3. The bus switch contributes no propagational delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25ns for 50pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagational delay to the system. Propagational delay of the bus switch when used in a system is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

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